CONTENTS

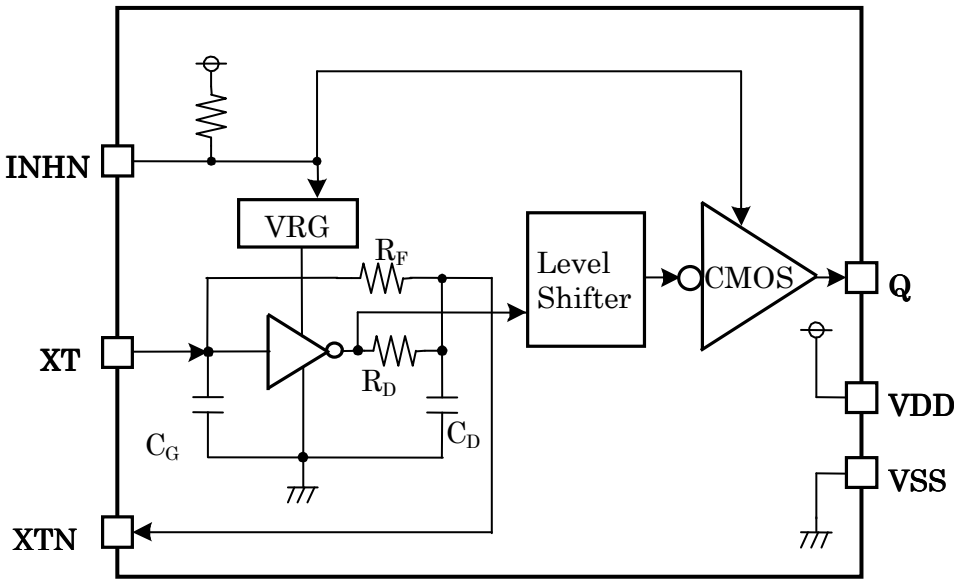
1. OVERVIEW

The CF5058Hx1/WF5058Hx1 series are crystal oscillator module CMOS ICs for +125°C operation. They support 20MHz to 60MHz fundamental-frequency, and have an oscillator amplifier, voltage regulator circuit and output buffer.

2. FEATURES

- Operating supply voltage: 1.60V to 3.63V
- Recommended oscillation frequency (Fundamental-frequency): 20MHz to 60MHz
- Current consumption :1.0mA typ. @ Hx1 ver. f_{OSC}=49MHz, V_{DD}=1.8V, no load
- Phase noise：Typical -98dBc/Hz @HA1ver., offset Frequency=10Hz, f_{OSC}=49MHz, V_{DD}=1.8V
- Operation temperature: -40 to +125°C
- Oscillator capacitors C_G, C_D built-in
- Output drive capability: ±4mA
- Output 3-state function
- Low standby current (oscillator stopped, power saving pull-up resistor)
- Oscillation detection circuit built-in

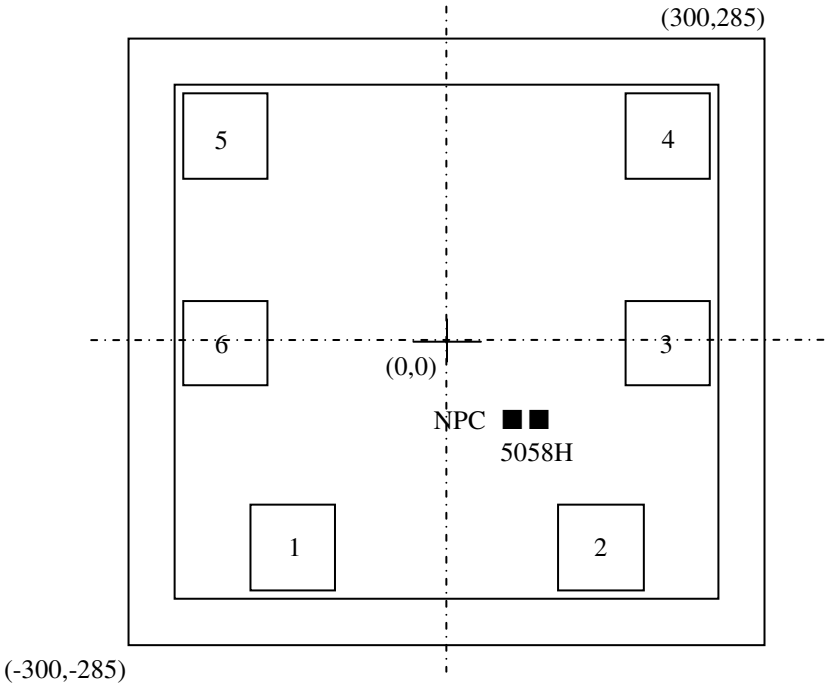
3. BLOCK DIAGRAM



4. PAD DIMENSIONS

(1) Chip size[*1]: X=0.60mm, Y=0.57mm
(2) Rear surface: V_{SS} potential
(3) Pad aperture size: 80um×80um
(4) Chip form

*1: The chip size is the value measured between scribe line centers.



Pad Dimensions Unit [µm]

No.	X	Y	Version name		
			HA1	HB1	HC1
1	-145.2	-193.5	**XT**	**XTN**	**XT**
2	145.2	-193.5	**XTN**	**XT**	**XTN**
3	208.5	-1.1	**VDD**	**INHN**	**VSS**
4	208.5	193.5	**Q**	**VSS**	**Q**
5	-208.5	193.5	**VSS**	**Q**	**VDD**
6	-208.5	-1.1	**INHN**	**VDD**	**INHN**

5. PAD DESCRIPTION

Symbol	I/O	Name	Description
XT	I	Oscillator input pin	・Crystal element connection pins ・Connect crystal between XT and XTN pins.
XTN	O	Oscillator output pin	
VDD	-	(+) supply pin	
Q	O	Output pin	・High-impedance output in standby mode
VSS	-	(-) supply pin	
INHN	I	Output state control input (Inhibit) pin	・Oscillator is stopped in standby mode when LOW. ・Pull-up resistor built-in

I : input pin, O : output pin

6. 5058Hxx SERIES CONFIGURATION

Version name	Oscillator frequency (Reference value)	Oscillator capacitance (pF) *1		Output stage			Standby state	
		C_G	C_D	Output duty level	Frequency	Output current	Oscillator stopped	Output
5058Hx1	Fundamental-frequency oscillation: 20MHz to 60MHz	12	18	$1/2V_{DD}$	f_{OSC}	±4mA	Yes	Hi-Z

*1: Excluding parasitic capacitance

7. ABSOLUTE MAXIMUM RATINGS

V_{SS}=0V

Parameter	Symbol	Conditions	Rating	Unit	Remarks
Supply voltage range	V_{DD}	Voltage between VDD and VSS	-0.3 to +4.0	V	*1
Input voltage range	V_{IN}	Input pins	-0.3 to V_{DD}+0.3	V	*1,*2
Output voltage range	V_{OUT}	Output pins	-0.3 to V_{DD}+0.3	V	*1,*2
Output current	I_{OUT}	Q output	±20	mA	*3
Junction temperature	T_j		150	°C	*3
Storage temperature range	T_{STG}	Chip form wafer form	-55 to +150	°C	*4

*1: Absolute maximum ratings are the values that must never exceed even for a moment. This product may suffer breakdown if any one of these parameter ratings is exceeded. Operation and characteristics are guaranteed only when the product is operated at recommended supply voltage range.
*2: V_{DD} is a V_{DD} value of recommended operating conditions.
*3: Do not exceed the absolute maximum ratings. If they are exceeded, a characteristic and reliability will be degraded.
*4: When stored alone in nitrogen or vacuum atmosphere.

8. RECOMMENDED OPERATING CONDITIONS

V_{SS}=0V

Parameter	Symbol	Conditions	MIN	TYP	MAX	Unit
Oscillator frequency *1	f_{OSC}	V_{DD}=1.6 to 3.63V	20		60	MHz
Output frequency	f_{OUT}	V_{DD}=1.6 to 3.63V,C_{LOUT}≤15pF	20		60	MHz
Operating supply voltage	V_{DD}	Voltage between VDD and VSS *2	1.60		3.63	V
Input voltage	V_{IN}	Input pins	V_{SS}		V_{DD}	V
Operating temperature	T_a		-40		+125	°C
Output load capacitance	C_{LOUT}	Q output			15	pF

*1: The oscillation frequency is a yardstick value and the oscillation frequency range is not guaranteed. Specifically, the characteristics can vary greatly due to crystal characteristics and mounting conditions, so the oscillation characteristics of components must be carefully evaluated.

*2: For stable operation of this product, please mount ceramic chip capacitor that is more than 0.01uF between VDD and VSS in close proximity to IC (within 3mm). Wiring pattern between IC and capacitor should be as thick as possible.

* Since it may influence the reliability if it is used out of the recommended operating conditions range, this product should be used within this range.

9. ELECTRICAL CHARACTERISTICS

9.1. DC Characteristics

V_{DD} = 1.60 to 3.63V, V_{SS} = 0V, T_a = -40 to +125°C unless otherwise noted

Parameter	Symbol	Conditions		MIN	TYP	MAX	Unit
Q pin HIGH-level output voltage	V_{OH}	measurement circuit 3, I_{OH}=-4mA		V_{DD} -0.4		V_{DD}	V
Q pin LOW-level output voltage	V_{OL}	measurement circuit 3, I_{OL}=4mA		0		0.4	V
INHN pin HIGH-level input voltage	V_{IH}	measurement circuit 4		$0.7V_{DD}$			V
INHN pin LOW-level input voltage	V_{IL}	measurement circuit 4				$0.3V_{DD}$	V
Q pin Output leakage current	I_Z	measurement circuit 5, INHN=LOW	$Q=V_{DD}$			10	µA
			$Q=V_{SS}$	-10			
Current consumption *1 (Hx1 version: fundamental frequency output)	I_{DD1}_3.3V	Measurement circuit 1, INHN=OPEN, no load, f_{OSC}=49MHz, f_{OUT}=49Hz	V_{DD}=3.3V		2.2	3.5	mA
	I_{DD1}_2.5V		V_{DD}=2.5V		1.4	2.5	
	I_{DD1}_1.8V		V_{DD}=1.8V		1.0	1.5	
Standby current	I_{ST}	Measurement circuit 1, INHN= V_{SS}	T_a=-40 to +85°C			10	µA
			T_a=-40 to +125°C			20	µA
INHN pin pull-up resistance	R_{PU1}	Measurement circuit 6		0.8	3	24	MΩ
	R_{PU2}	Measurement circuit 6		30	70	150	kΩ
Oscillator feedback resistance	R_f			50	100	200	kΩ
Oscillator capacitance	C_G	Confirmed using monitor pattern on the wafer. Design value, excluding parasitic capacitance		9.6	12	15	pF
	C_D			14.4	18	22.5	

*1: The consumption current $I_{DD}(C_{LOUT})$ with a load capacitance (C_{LOUT}) connected to the Q pin is given by the following equation, where I_{DD} is the no-load consumption current and f_{OUT} is the output frequency.

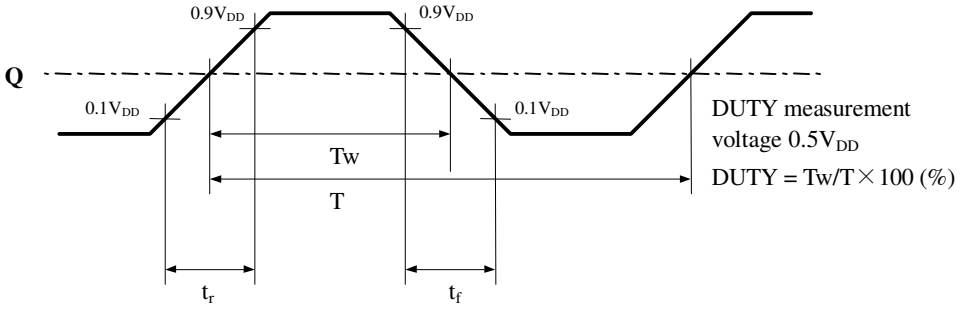
$$I_{DD}(C_{LOUT})[mA] = I_{DD}[mA] + C_{LOUT}[pF] \times V_{DD}[V] \times f_{OUT}[MHz] \cdot 10^{-3}$$

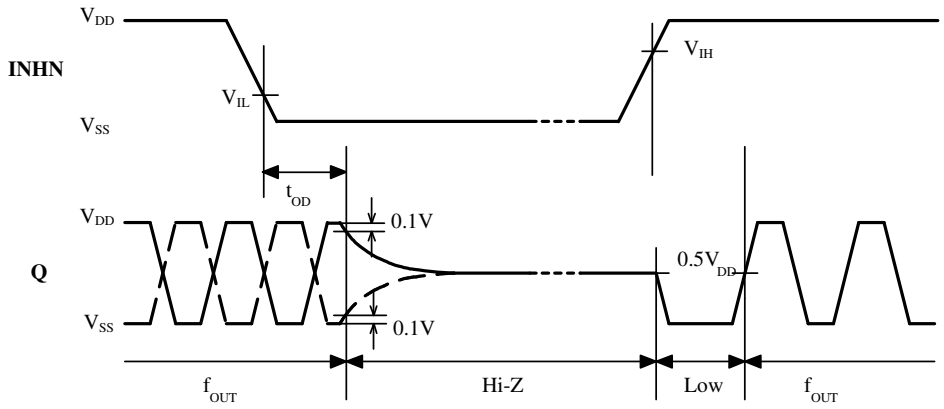
9.2. AC Characteristics

V_{DD} = 1.60 to 3.63V, V_{SS} = 0V, T_a = -40 to +125°C unless otherwise noted

Parameter	Symbol	Conditions	MIN	TYP	MAX	Unit
Q pin Output rise time	t_{r1}	Measurement circuit 1, C_{LOUT}=15pF, $0.1V_{DD} \rightarrow 0.9V_{DD}$, V_{DD}=2.25 to 3.63V		1.5	5.0	ns
	t_{r2}	Measurement circuit 1, C_{LOUT}=15pF, $0.1V_{DD} \rightarrow 0.9V_{DD}$, V_{DD}=1.60 to 2.25V		2.0	6.0	
Q pin Output fall time	t_{f1}	Measurement circuit 1, C_{LOUT}=15pF, $0.9V_{DD} \rightarrow 0.1V_{DD}$, V_{DD}=2.25 to 3.63V		1.5	5.0	ns
	t_{f2}	Measurement circuit 1, C_{LOUT}=15pF, $0.9V_{DD} \rightarrow 0.1V_{DD}$, V_{DD}=1.60 to 2.25V		2.0	6.0	
Q pin Output duty cycle	DUTY	Measurement circuit 1, T_a=25°C, C_{LOUT}=15pF, V_{DD}=1.60 to 3.63V	45	50	55	%
Q pin Output disable delay time	t_{OD}	Measurement circuit 2, T_a=25°C, $C_{LOUT} \leq$15pF			200	ns

TIMING DIAGRAMS





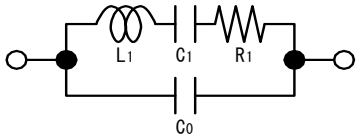
・When INHN goes HIGH to LOW, the Q output becomes high impedance.
・When INHN goes LOW to HIGH, the Q output goes LOW once and then becomes normal output operation after having detected oscillation signals.

10. REFERENCE DATA (5058 TYPICAL CHARACTERISTICS)

The following characteristics are measured using the crystal below.
Note that the characteristics will vary with the crystal used.

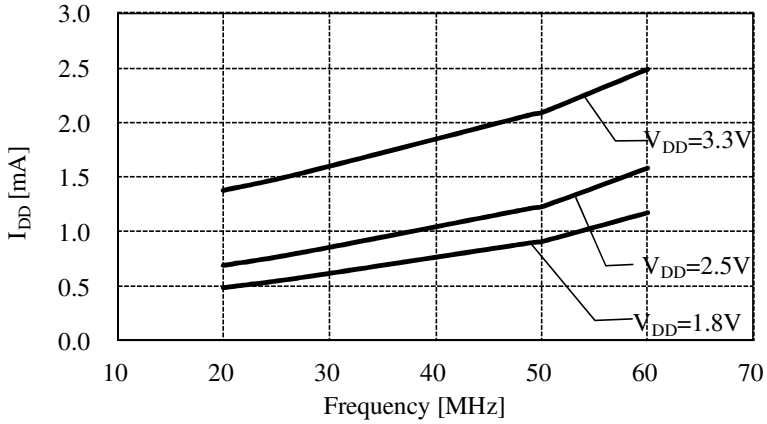
Crystal used for measurement

Parameter	49.15MHz
C_0(pF)	0.9
R_1(Ω)	10



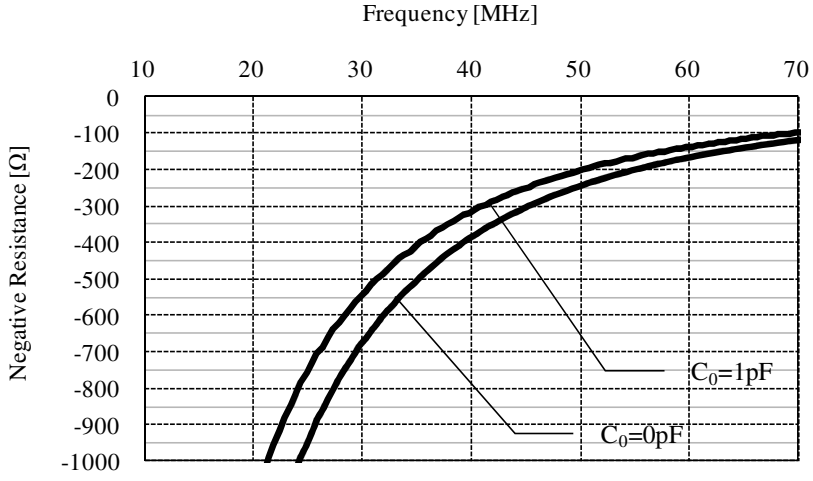
Crystal parameters

10.1. Current Consumption



5058Hx1, T_a=25°C, no load

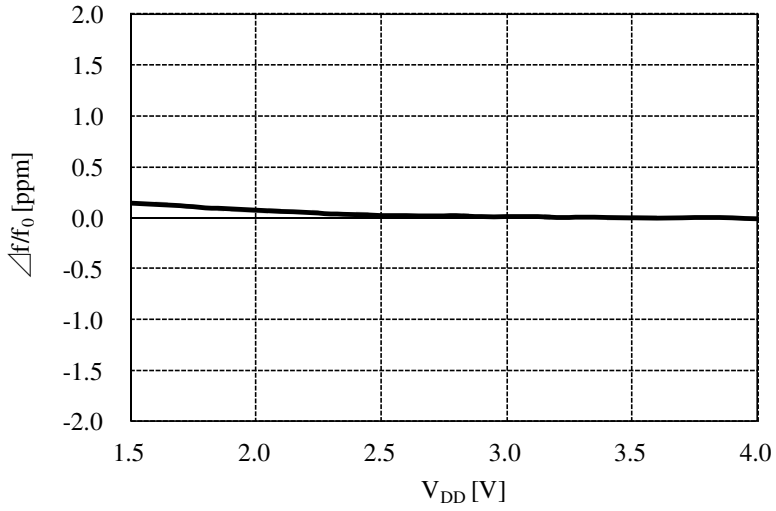
10.2. Negative Resistance



5058Hx1, V_{DD}=1.8V, T_a=25°C
Measurement equipment: Agilent Impedance analyzer 4396B

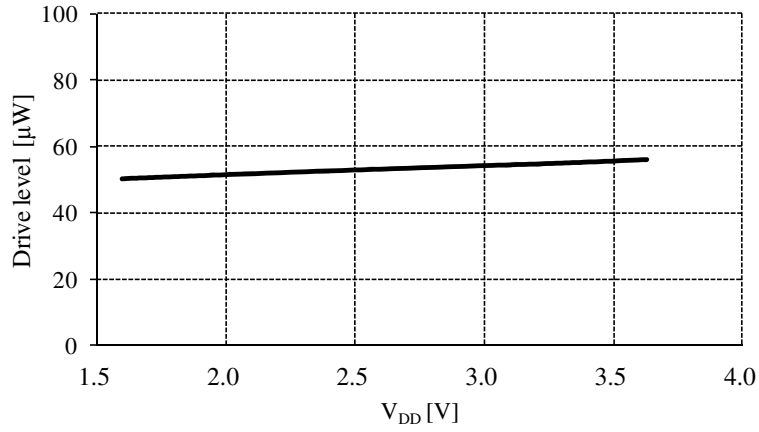
The figures show the measurement result of the crystal equivalent circuit C_0 capacitance, connected between the XT and XTN pins. They were performed with Agilent 4396B using the NPC test jig.
They may vary in a measurement jig, and measurement environment.

10.3. Frequency Deviation with Voltage



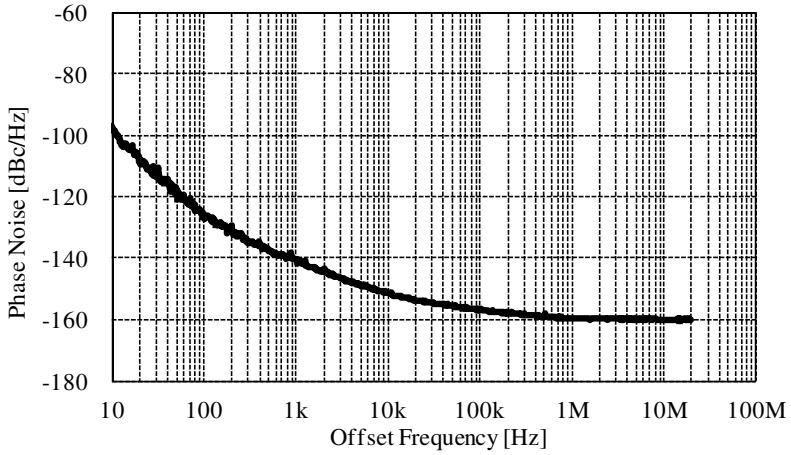
5058Hx1, f_{OSC}=49.15MHz, T_a=25°C, 3.3V std.

10.4. Drive Level



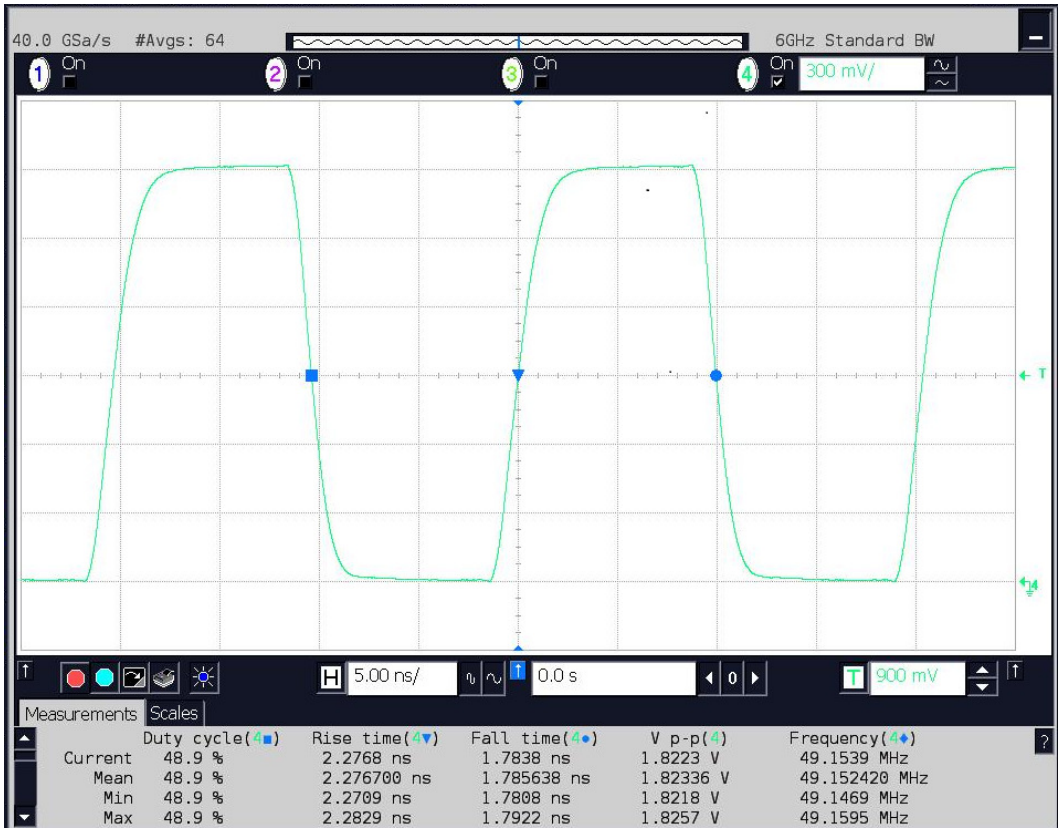
5058Hx1, f_{OSC}=49.15MHz, T_a=25°C

10.5. Phase Noise



5058Hx1, f_{OSC}=49.15MHz, V_{DD}=1.8V, T_a=25°C
Measurement equipment: Signal Source Analyzer Agilent E5052B

10.6. Output Waveform



5058Hx1 version, V_{DD}=1.8V, f_{OUT}=49.15MHz, C_{LOUT}=15pF, T_a: Room temperature

Measurement equipment: Oscilloscope Agilent DSO80604B

11. FUNCTIONAL DESCRIPTION

11.1. INHN Function

Q output is stopped and becomes high impedance.

INHN	Q	Oscillator
HIGH or Open	f_{OUT}	Operating
LOW	Hi-Z	Stopped

11.2. Power Saving Pull-up Resistor

The INHN pin pull-up resistance changes its value to R_{PU1} or R_{PU2} in response to the input level (HIGH or LOW).

When INHN is tied to LOW level, the pull-up resistance becomes large (R_{PU1}), thus reducing the current consumed by the resistance. When INHN is left open circuit or tied to HIGH level, the pull-up resistance becomes small (R_{PU2}), thus internal circuit of INHN becomes HIGH level.

Consequently, the IC is less susceptible to the effects of noise, helping to avoid problems such as the output stopping suddenly.

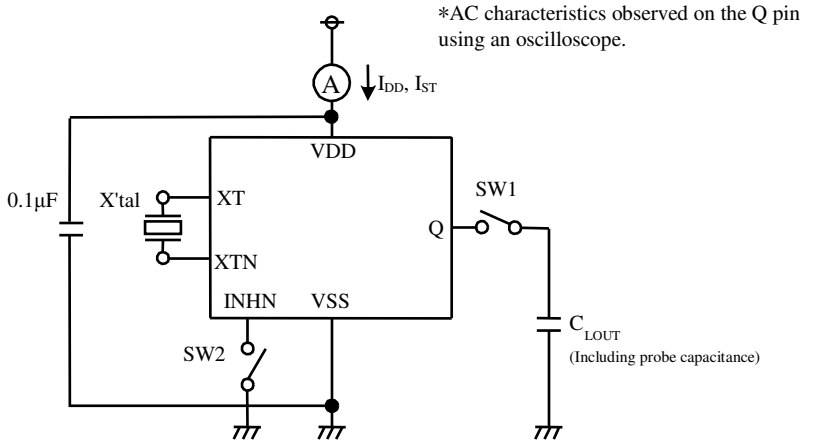
11.3. Oscillation Detection Function

The 5058 series have an oscillation detection circuit.

The oscillation detection circuit disables the output until crystal oscillation becomes stable when oscillation circuit starts up. This function avoids the abnormal oscillation in the initial power up and in a reactivation by INHN.

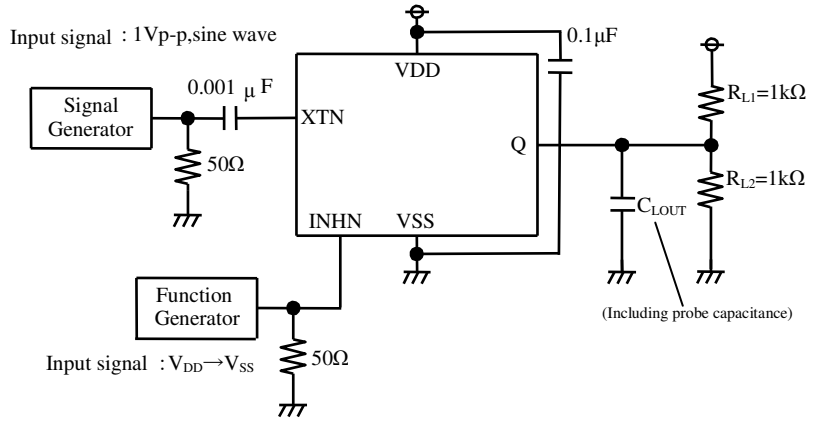
12. MEASUREMENT CIRCUITS

- Measurement circuit 1 Parameters: I_{DD}, I_{ST}, DUTY, t_r, t_f

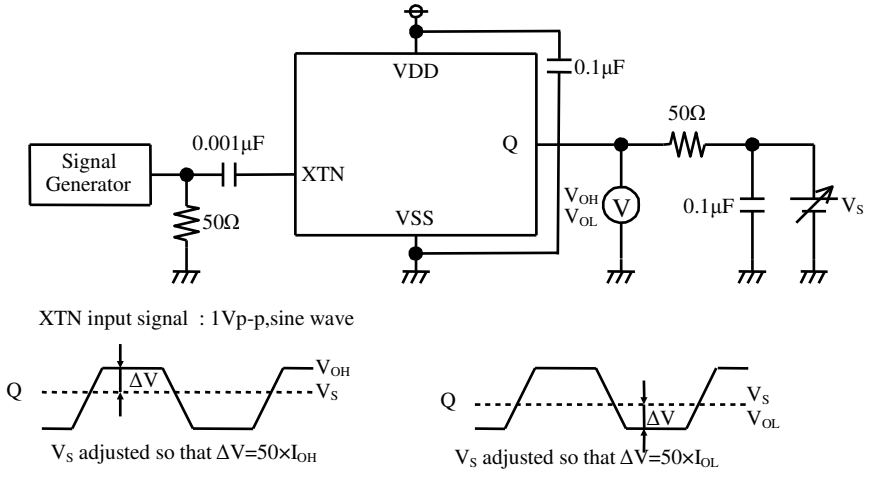


Parameter	SW1	SW2
I_{DD}	OFF	OFF
I_{ST}	ON or OFF	ON
DUTY,t_r,t_f	ON	OFF

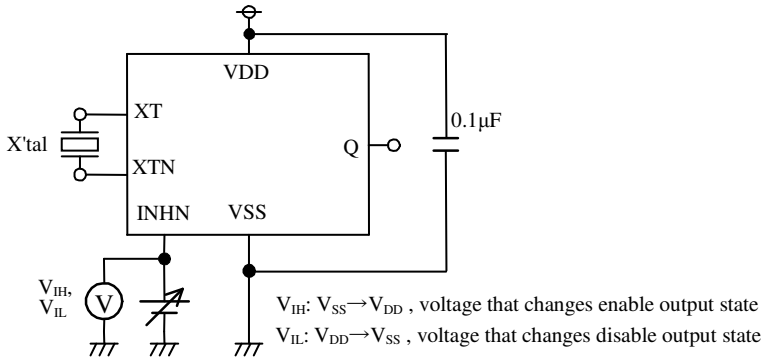
- Measurement circuit 2 Parameter: t_{OD}



- Measurement circuit 3 Parameter: V_{OH}, V_{OL}

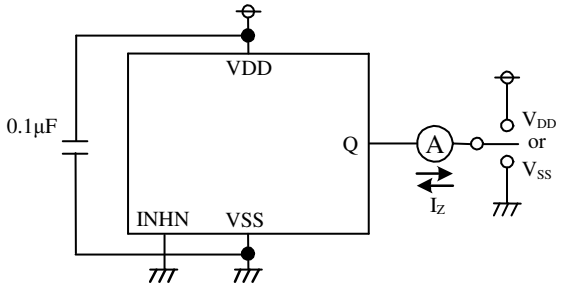


- Measurement circuit 4 Parameter: V_{IH}, V_{IL}

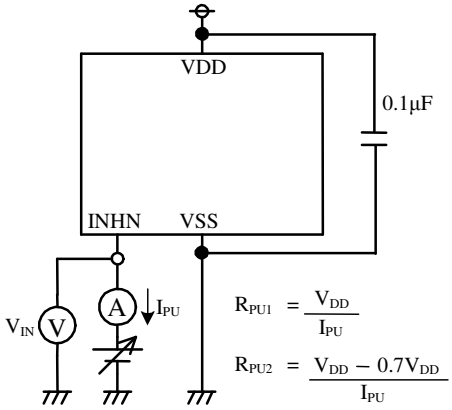


V_{IH}: $V_{SS} \rightarrow V_{DD}$, voltage that changes enable output state
V_{IL}: $V_{DD} \rightarrow V_{SS}$, voltage that changes disable output state

- Measurement circuit 5 Parameter: I_Z



- Measurement circuit 6 Parameter: R_{PU1}, R_{PU2}



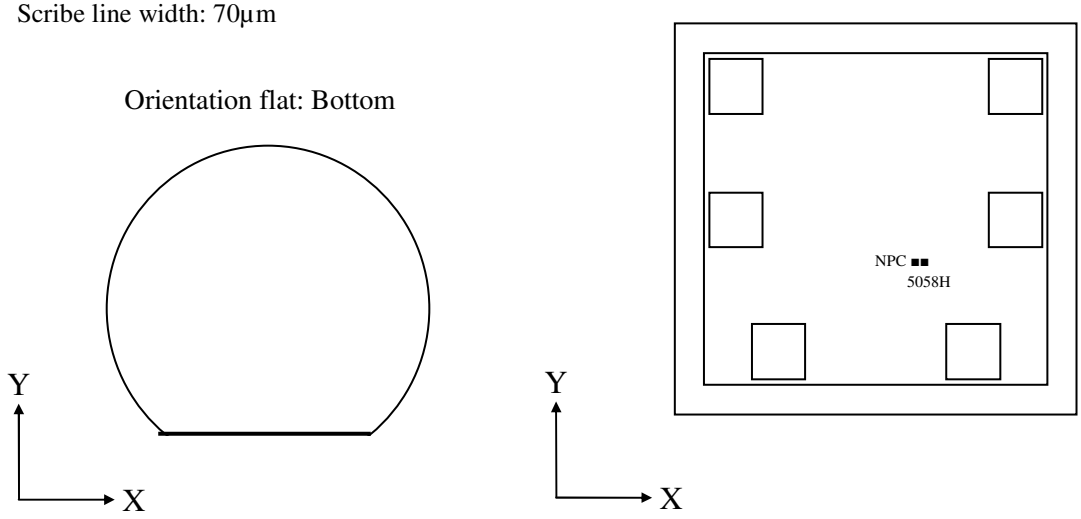
$$R_{PU1} = \frac{V_{DD}}{I_{PU}} \quad (V_{IN} = 0V)$$

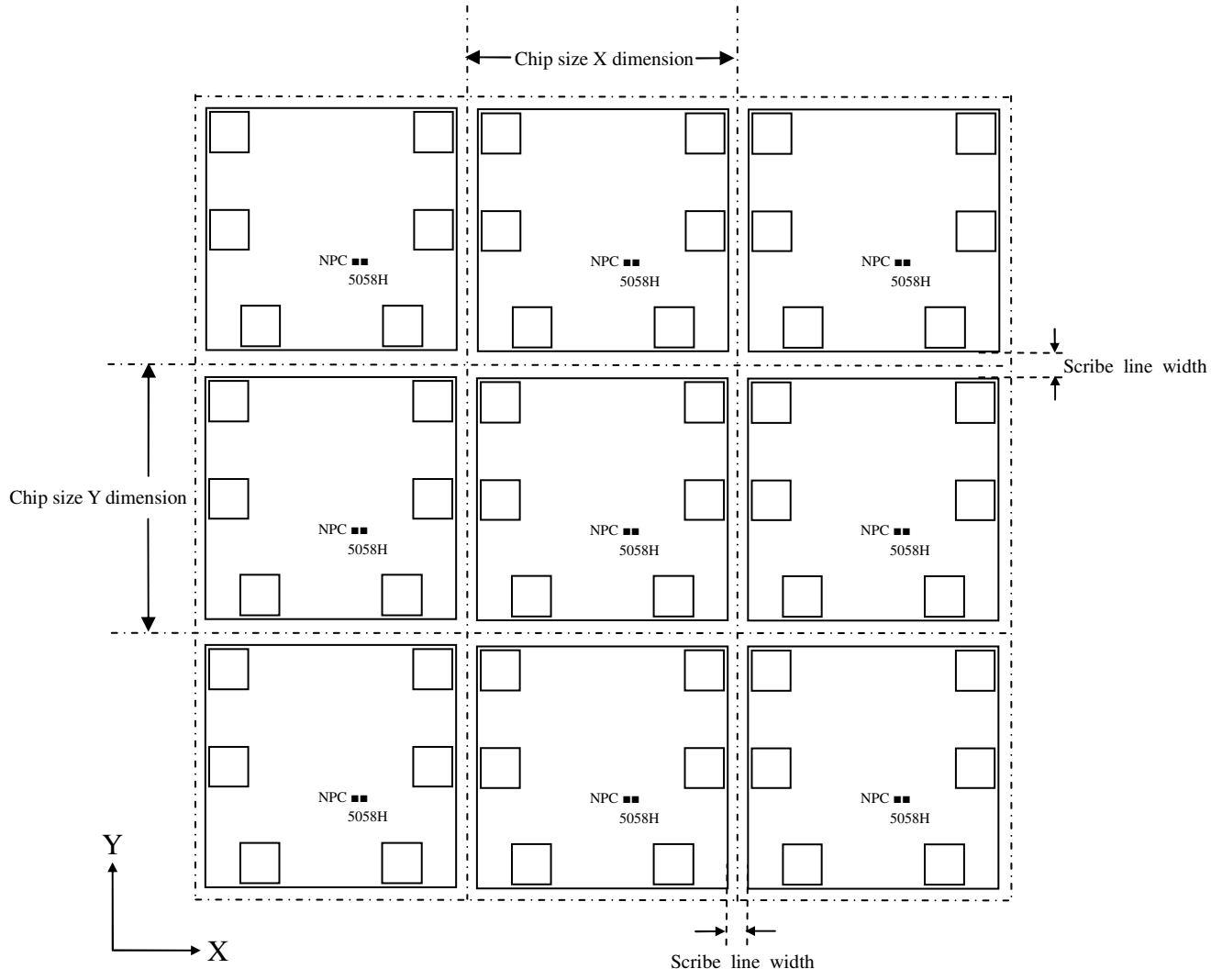
$$R_{PU2} = \frac{V_{DD} - 0.7V_{DD}}{I_{PU}} \quad (V_{IN} = 0.7V_{DD})$$

13. WAFER SURFACE ALIGNMENT DIAGRAM

Wafer size:150mm±0.5mm
Scribe line width: 70μm

Orientation flat: Bottom





14. USAGE AND PRECAUTIONS

This product is designed and manufactured to the generally accepted standards of reliability as expected for use in general electronic and electrical equipment, such as personal equipment, machine tools, and measurement equipment. This product is not designed and manufactured to be used in any other special equipment requiring extremely high level of reliability and safety, such as aerospace equipment, nuclear power control equipment, medical equipment, transportation equipment, disaster prevention equipment, security equipment.
If you wish to use this product in equipment requiring extremely high level of reliability, please contact our sales department or representative in advance.
In the event that this product is used in such equipment, please take scrupulous care and apply fail-safe techniques including redundancy and malfunction prevention in order to prevent damage to life, health, property, or infrastructure etc. in case there is some malfunction in the product.

Please pay your attention to the following points at time of using the products shown in this document.

1. The products shown in this document (hereinafter "Products") are designed and manufactured to the generally accepted standards of reliability as expected for use in general electronic and electrical equipment, such as personal equipment, machine tools and measurement equipment. The Products are not designed and manufactured to be used in any other special equipment requiring extremely high level of reliability and safety, such as aerospace equipment, nuclear power control equipment, medical equipment, transportation equipment, disaster prevention equipment, security equipment. The Products are not designed and manufactured to be used for the apparatus that exerts harmful influence on the human lives due to the defects, failure or malfunction of the Products.
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